

PRECISION DUAL ULTRA MICROPOWER CMOS OPERATIONAL AMPLIFIER

GENERAL DESCRIPTION

The ALD2736A/ALD2736 is a precision dual low-cost high-slew-rate high-performance ultra micropower monolithic CMOS operational amplifier intended for a broad range of analog applications using $\pm 1 \text{V}$ to $\pm 5 \text{V}$ dual power supply systems, as well as $\pm 2 \text{V}$ to $\pm 10 \text{V}$ battery operated systems. All device characteristics are specified for $\pm 5 \text{V}$ single supply or $\pm 2.5 \text{V}$ dual supply systems. Typical supply current is $25 \mu A$ per op amp at 5V supply voltage. It is manufactured with Advanced Linear Devices' enhanced EPAD® silicon gate CMOS process.

The ALD2736A/ALD2736 is designed to offer high performance for a wide range of applications requiring very low power dissipation. It has been developed specifically for the +5V single battery or $\pm 1V$ to $\pm 5V$ dual battery user and offers the popular industry standard single operational amplifier pin configuration.

Several important characteristics of the device make application easier to implement at those voltages. First, the operational amplifier can operate with rail to rail input and output voltages. This means the signal input voltage and output voltage can be close to or equal to the positive and negative supply voltages. This feature allows numerous analog serial stages and flexibility in input signal bias levels. Second, the device was designed to accommodate mixed applications where digital and analog circuits may operate off the same power supply or battery. Third, the output stage can typically drive up to 25pF capacitive and $20 \mathrm{K} \Omega$ resistive loads.

These features, combined with extremely low input currents, high open loop voltage gain of 100V/mV, useful bandwidth of 400KHz, a slew rate of $0.17V/\mu s$, low offset voltage and temperature drift, make the ALD2736A/ALD2736 a versatile, micropower operational amplifier.

The ALD2736A/ALD2736, designed and fabricated with silicon gate CMOS technology, offers on-chip offset voltage trimming, allowing the device to be used without nulling in most applications. It is also designed to offer tolerance to over-voltage input spikes of 300mV beyond supply rails, high open loop voltage gain, and robust operation at temperature extremes. Additionally, robust design and rigorous screening make this device especially suitable for operation in temperature-extreme environments and rugged conditions.

ORDERING INFORMATION ("L" suffix denotes lead-free (RoHS))

Opera	Operating Temperature Range							
0°C to +70°C	0°C to +70°C	-55°C to +125°C						
8-Pin	8-Pin	8-Pin						
Small Outline	Plastic Dip	CERDIP						
Package (SOIC)	Package	Package						
ALD2736ASAL	ALD2736APAL	ALD2736ADA						
ALD2736SAL	ALD2736PAL	ALD2736DA						

^{*} Contact factory for leaded (non-RoHS) or high temperature versions.

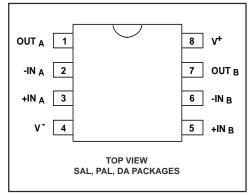
FEATURES & BENEFITS

- Typical 25μA supply current per amplifier
- All parameters specified for +5V single supply or ± 2.5V dual supply systems
- · Rail to rail input and output voltage ranges
- No frequency compensation required -- unity gain stable
- Extremely low input bias currents -- 0.01pA typical
- Ideal for high source impedance applications
- Dual power supplies ±1.0V to ±5.0V
- Single power supply +2.0V to +10.0V
- High voltage gain -- typically 100V/mV @ ±2.5V (100dB)
- Drive as low as a 20KΩ load
- · Output short circuit protected
- Unity gain bandwidth of 0.4MHz
- Slew rate of 0.17V/μs
- Ultra Micropower symmetrical complementary output drive
- Suitable for rugged, temperature-extreme environments

APPLICATIONS

- Voltage amplifier
- Voltage follower/buffer
- Charge integrator
- Photodiode amplifier
- · Data acquisition systems
- · High performance portable instruments
- · Biochemical probe interface
- · Signal conditioning circuits
- Sensor and transducer amplifiers
- Low leakage amplifiers
- Precision Sample and Hold amplifiers
- Active filters
- Picoammeter
- Current to voltage converter

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS

Supply voltage, V+	10.6V
Differential input voltage range	-0.3V to V++0.3V
Power dissipation	600mW
Operating temperature range SAL, PAL packages	0°C to +70°C
DA package	55°C to +125°C
Storage temperature range	65°C to +150°C
Lead temperature, 10 seconds	+260°C

CAUTION: ESD Sensitive Device. Use static control procedures in ESD controlled environment.

OPERATING ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C\ V_S = \pm 2.5V\ unless otherwise specified$

			ALD2736A			ALD2736			Test
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Conditions
Supply Voltage	Vs V+	±1.0 2.0		±5.0 10.0	±1.0 2.0		±5.0 10.0	V V	Dual Supply Single Supply
Input Offset Voltage	Vos			1.0 1.5			2.0 2.5	mV mV	RS ≤ 100KΩ 0°C ≤ T _A ≤ +70°C
Input Offset Current	los		0.01	10 240		0.01	10 240	pA pA	T _A = 25°C 0°C ≤ T _A ≤ +70°C
Input Bias Current	IB		0.01	10 300		0.01	10 300	pA pA	T _A = 25°C 0°C ≤ T _A ≤ +70°C
Input Voltage Range	VIR	-0.3 -2.8		+5.3 +2.8	-0.3 -2.8		+5.3 +2.8	V V	V+ = +5V VS = ±2.5V
Input Resistance	RIN		10 ¹⁴			10 ¹⁴		Ω	
Input Offset Voltage Drift	TCVos		5			5		μV/°C	RS ≤ 100KΩ
Power Supply Rejection Ratio	PSRR		82 82			82 82		dB dB	R _S ≤ 100KΩ 0°C ≤ T _A ≤ +70°C
Common Mode Rejection Ratio	CMRR		83 83			83 83		dB dB	R _S ≤ 100KΩ 0°C ≤ T _A ≤ +70°C
Large Signal Voltage Gain	Ay		100			100		V/mV	$R_L = 1M\Omega$
Output Voltage Range	VO low	4.99	0.001 4.999	0.01	4.99	0.001 4.999	0.01	V V	$R_{L} = 1M\Omega$ $0^{\circ}C \le T_{A} \le +70^{\circ}C$
	VO low	2.40	-2.48 2.48	-2.40	2.40	-2.48 2.40	-2.40	V	R _L =100KΩ 0°C ≤ T _A ≤ +70°C
Output Short Circuit Current	ISC		200			200		μΑ	
Supply Current	IS		50	85		50	100	μА	VIN = 0V, No Load
Power Dissipation	PD			425			500	μW	VS = ±2.5V
Input Capacitance	C _{IN}		1			1		pF	
Bandwidth	BW		400			400		KHz	
Slew Rate	SR		.17			.17		V/μs	$AV = +1$, $RL = 1M\Omega$

OPERATING ELECTRICAL CHARACTERISTICS (cont'd)

 $T_A = 25^{\circ}C$ $V_S = \pm 2.5V$ unless otherwise specified (cont'd)

		A	LD2736/	\	1	ALD2736			
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Rise time	tr		1.0			1.0		μS	R _L = 1MΩ
Overshoot Factor			20			20		%	$R_L = 1M\Omega$, $C_L = 25pF$
Settling Time	ts		10.0			10.0		μS	0.1%, A _V = -1, R _L = 1MΩ, C _L = 25pF

$T_A = 25^{\circ}C$ $V_S = \pm 1.0V$ unless otherwise specified

		-	ALD2736	A		ALD2736			
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Power Supply Rejection Ratio	PSRR		70			70		dB	R _S ≤ 1MΩ
Common Mode Rejection Ratio	CMRR		70			70		dB	R _S ≤ 1MΩ
Large Signal Voltage Gain	Av		50			50		V/mV	R _L = 1MΩ
Output Voltage Range	V _O low V _O high	0.9	-0.95 0.95	-0.9	0.9	-0.95 0.95	-0.9	V	$R_L = 1M\Omega$
Bandwidth	B _W		0.3			0.3		MHz	
Slew Rate	S _R		0.17			0.17		V/μs	$A_V = +1, C_L = 50pF$

$V_S = \pm 2.5 V -55^{\circ}C \le T_A \le +125^{\circ}C$ unless otherwise specified

·			ALD2736	Α	ALD2736				
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Input Offset Voltage	Vos			2.0			3.0	mV	RS ≤ 100KΩ
Input Offset Current	los			2.0			2.0	nA	
Input Bias Current	IB			2.0			2.0	nA	
Power Supply Rejection Ratio	PSRR		75			75		dB	R _S ≤ 1MΩ
Common Mode Rejection Ratio	CMRR		83			83		dB	R _S ≤ 1MΩ
Large Signal Voltage Gain	AV		50			50		V/mV	R _L = 1MΩ
Output Voltage Range	VO low	2.30	-2.40 2.40	-2.30	2.30	-2.40 2.40	-2.30	V V	R _L = 1MΩ

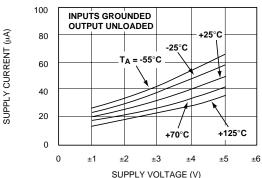
Design & Operating Notes:

- 1. The ALD2736A/ALD2736 CMOS operational amplifier uses a 3 gain stage architecture and an improved frequency compensation scheme to achieve large voltage gain, high output driving capability, and better frequency stability. In a conventional CMOS operational amplifier design, compensation is achieved with a pole splitting capacitor together with a nulling resistor. This method is, however, very bias dependent and thus cannot accommodate the large range of supply voltage operation as is required from a stand alone CMOS operational amplifier. The ALD2736A/ALD2736 is internally compensated for unity gain stability using a novel scheme that does not use a nulling resistor. This scheme produces a clean single pole roll off in the gain characteristics while providing for more than 70 degrees of phase margin at the unity gain frequency.
- The ALD2736A/ALD2736 has complementary p-channel and nchannel input differential stages connected in parallel to accomplish rail to rail common mode input voltage ranges. This means that with the ranges of common mode input voltage close to the power supplies, one of the two differential stages is switched off internally. To maintain compatibility with other operational amplifiers, this switching point has been selected to be about 1.5V below the positive supply voltage. Since offset voltage trimming on the ALD2736A/ ALD2736 is made when the input voltage is symmetrical to the supply voltages, this internal switching does not affect a large variety of applications such as an inverting amplifier or non-inverting amplifier with a gain larger than 2.5 (5V operation), where the common mode voltage does not make excursions below this switching point. The user should, however, be aware that this switching does take place if the operational amplifier is connected as a unity gain buffer and should make provisions in the design to allow for input offset voltage variations
- 3. The input bias and offset currents are essentially input protection diode reverse bias leakage currents, and are typically 0.01pA at room temperature. This low input bias current assures that the analog signal from the source will not be distorted by input bias currents.

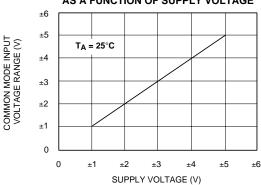
- Normally, this extremely high input impedance of greater than $10^{14}\Omega$ would not be a problem as the source impedance would limit the node impedance. However, for applications where source impedance is very high, it may be necessary to limit noise and hum pickup through proper shielding.
- 4. The output stage consists of class AB complementary output drivers, capable of driving a low resistance load. The output voltage swing is limited by the drain to source on-resistance of the output transistors as determined by the bias circuitry, and the value of the load resistor. When connected in the voltage follower configuration, the oscillation resistant feature, combined with the rail to rail input and output feature, makes an effective analog signal buffer for medium to high source impedance sensors, transducers, and other circuit networks.
- 5. The ALD2736A/ALD2736 operational amplifier has been designed to provide full static discharge protection. Internally, the design has been carefully implemented to minimize latch up. However, care must be exercised when handling the device to avoid strong static fields that may degrade a diode junction, causing increased input leakage currents. In using the operational amplifier, the user is advised to power up the circuit before, or simultaneously with, any input voltages applied and to limit input voltages to not exceed 0.3V of the power supply voltage levels.
- 6. The ALD2736A/ALD2736, with its micropower operation, offers numerous benefits in reduced power supply requirements, less noise coupling and current spikes, less thermally induced drift, better overall reliability due to lower self heating, and lower input bias current. It requires practically no warm up time as the chip junction heats up to only 0.1°C above ambient temperature under most operating conditions.
- The ALD2736A/ALD2736 has an internal design architecture that provides robust high temperature operation. Contact factory for custom screening versions.

TYPICAL PERFORMANCE CHARACTERISTICS

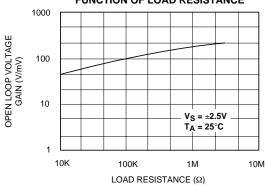
SUPPLY CURRENT AS A FUNCTION OF SUPPLY VOLTAGE



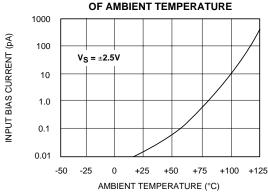
COMMON MODE INPUT VOLTAGE RANGE AS A FUNCTION OF SUPPLY VOLTAGE



OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF LOAD RESISTANCE

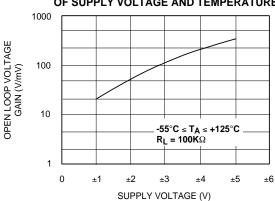


INPUT BIAS CURRENT AS A FUNCTION OF AMBIENT TEMPERATURE

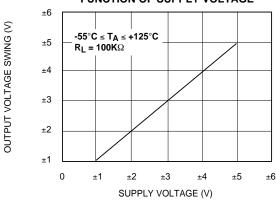


TYPICAL PERFORMANCE CHARACTERISTICS (cont'd)

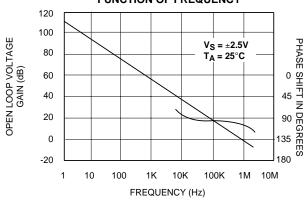
OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF SUPPLY VOLTAGE AND TEMPERATURE



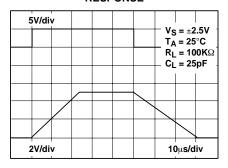
OUTPUT VOLTAGE SWING AS A FUNCTION OF SUPPLY VOLTAGE



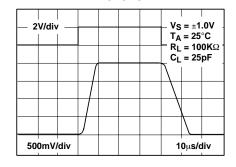
OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF FREQUENCY



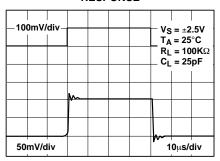
LARGE-SIGNAL TRANSIENT RESPONSE



LARGE-SIGNAL TRANSIENT RESPONSE

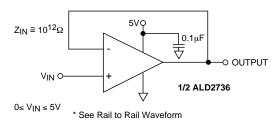


SMALL-SIGNAL TRANSIENT RESPONSE

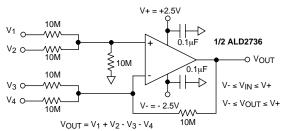


TYPICAL APPLICATIONS

RAIL-TO-RAIL VOLTAGE FOLLOWER/BUFFER

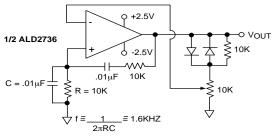


HIGH INPUT IMPEDANCE RAIL-TO-RAIL PRECISION DC SUMMING AMPLIFIER



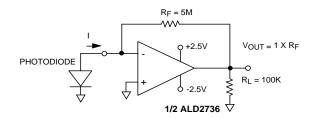
 R_{IN} = 10M Ω Accuracy limited by resistor tolerances and input offset voltage

WIEN BRIDGE OSCILLATOR (RAIL-TO-RAIL) SINE WAVE GENERATOR

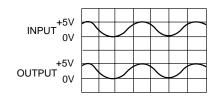


* See Rail to Rail Waveform

PHOTO DETECTOR CURRENT TO VOLTAGE CONVERTER

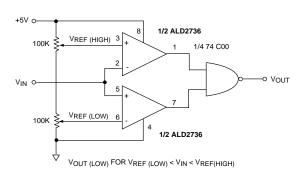


RAIL-TO-RAIL WAVEFORM

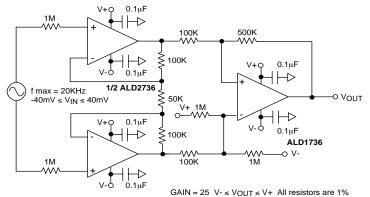


Performance waveforms. Upper trace is the output of a Wien Bridge Oscillator. Lower trace is the output of Rail-to-rail voltage follower.

RAIL-TO-RAIL WINDOW COMPARATOR



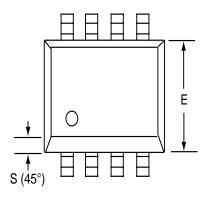
LOW VOLTAGE INSTRUMENTATION AMPLIFIER

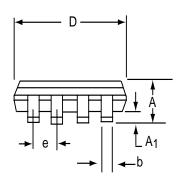


1/2 ALD2736 V+=+1.0V V-=-1.0V Short Circuit Input Current 1 μ A

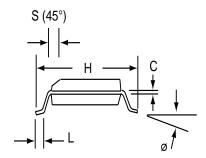
SOIC-8 PACKAGE DRAWING

8 Pin Plastic SOIC Package



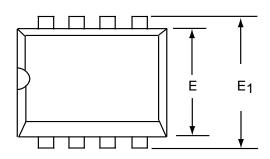


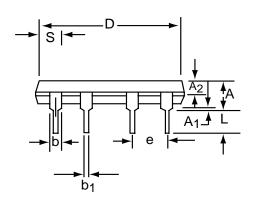
	Millim	neters	Inches			
Dim	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.25	0.004	0.010		
b	0.35	0.45	0.014	0.018		
С	0.18	0.25	0.007	0.010		
D-8	4.69	5.00	0.185	0.196		
E	3.50	4.05	0.140	0.160		
е	1.27	BSC	0.050 BSC			
н	5.70	6.30	0.224	0.248		
L	0.60	0.937	0.024	0.037		
Ø	0°	8°	0°	8°		
S	0.25	0.50	0.010	0.020		



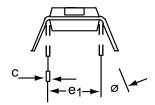
PDIP-8 PACKAGE DRAWING

8 Pin Plastic DIP Package



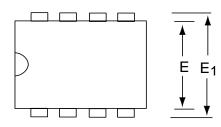


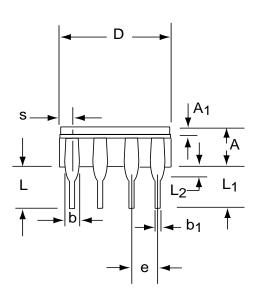
	Millin	neters	Inc	hes
Dim	Min	Max	Min	Max
Α	3.81	5.08	0.105	0.200
A ₁	0.38	1.27	0.015	0.050
A ₂	1.27	2.03	0.050	0.080
b	0.89	1.65	0.035	0.065
b ₁	0.38	0.51	0.015	0.020
С	0.20	0.30	0.008	0.012
D-8	9.40	11.68	0.370	0.460
E	5.59	7.11	0.220	0.280
E ₁	7.62	8.26	0.300	0.325
е	2.29	2.79	0.090	0.110
e ₁	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
S-8	1.02	2.03	0.040	0.080
Ø	0°	15°	0°	15°

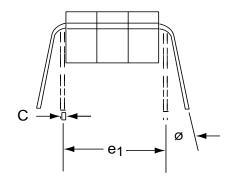


CERDIP-8 PACKAGE DRAWING

8 Pin CERDIP Package







	Millim	neters	Inc	hes	
Dim	Min	Max	Min	Max	
Α	3.55	5.08	0.140	0.200	
A ₁	1.27	2.16	0.050	0.085	
b	0.97	1.65	0.038	0.065	
b ₁	0.36	0.58	0.014	0.023	
С	0.20	0.38	0.008	0.015	
D-8		10.29		0.405	
Е	5.59	7.87	0.220	0.310	
E ₁	7.73	8.26	0.290	0.325	
е	2.54 E	BSC	0.100 BSC		
e ₁	7.62 E	BSC	0.300	BSC	
L	3.81	5.08	0.150	0.200	
L ₁	3.18		0.125		
L ₂	0.38	1.78	0.015	0.070	
S		2.49		0.098	
Ø	0°	15°	0°	15°	